



勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

Si4431ADY
Vishay Siliconix

P-Channel 30-V (D-S) MOSFET

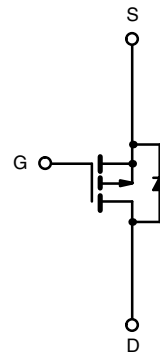
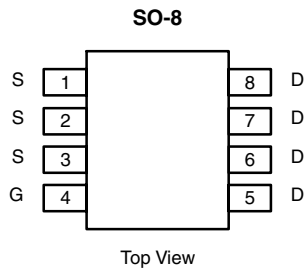
PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-30	0.030 @ $V_{GS} = -10$ V	-7.2
	0.052 @ $V_{GS} = -4.5$ V	-5.5

FEATURES

- TrenchFET® Power MOSFET



RoHS
 COMPLIANT



P-Channel MOSFET

Ordering Information: Si4431ADY-T1
 Si4431ADY-T1—E3 (Lead (Pb)-free)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)					
Parameter	Symbol	10 secs	Steady State	Unit	
Drain-Source Voltage	V_{DS}	-30		V	
Gate-Source Voltage	V_{GS}	± 20			
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	I_D	$T_A = 25^\circ\text{C}$	-7.2	-5.3	A
		$T_A = 70^\circ\text{C}$	-5.8	-4.2	
Pulsed Drain Current	I_{DM}	-30			
continuous Source Current (Diode Conduction) ^a	I_S	-2.1	-1.3		
Maximum Power Dissipation ^a	P_D	$T_A = 25^\circ\text{C}$	2.5	1.35	W
		$T_A = 70^\circ\text{C}$	1.6	0.87	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150		$^\circ\text{C}$	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 10$ sec	35	50	$^\circ\text{C}/\text{W}$
		Steady State	75	92	
Maximum Junction-to-Foot	R_{thJF}	17	25		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

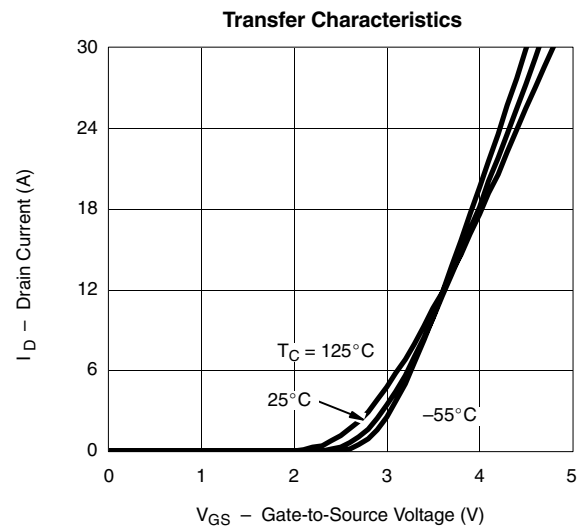
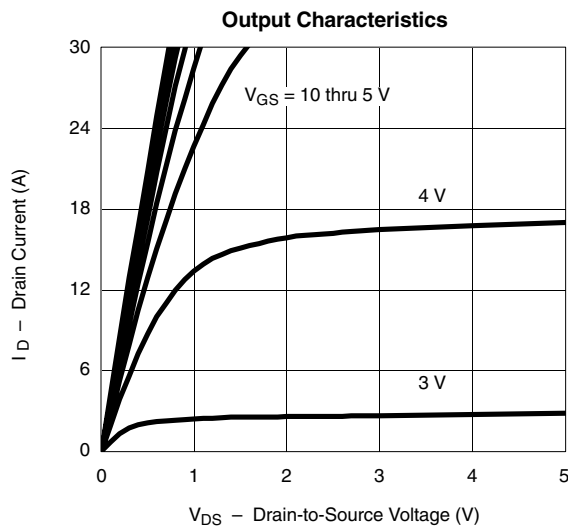


SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.0		-3.0	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -30 V, V _{GS} = 0 V, T _J = 70 °C			-10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = -5 V, V _{GS} = -10 V	-30			A
		V _{DS} = -5 V, V _{GS} = -4.5 V	-7			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = -10 V, I _D = -7.2 A		0.024	0.030	Ω
		V _{GS} = -4.5 V, I _D = -5.0 A		0.040	0.052	
Forward Transconductance ^a	g _{fs}	V _{DS} = -15 V, I _D = -7.2 A		14		S
Diode Forward Voltage ^a	V _{SD}	I _S = -2.1 A, V _{GS} = 0 V		-0.78	-1.1	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = -15 V, V _{GS} = -5 V, I _D = -7.2 A		12	20	nC
Gate-Source Charge	Q _{gs}			4.7		
Gate-Drain Charge	Q _{gd}			3.7		
Gate Resistance	R _G			3.1	4.7	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = -15 V, R _L = 15 Ω I _D ≅ -1 A, V _{GEN} = -10 V, R _G = 6 Ω		12	20	ns
Rise Time	t _r			15	20	
Turn-Off Delay Time	t _{d(off)}			40	60	
Fall Time	t _f			20	25	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = -2.1 A, di/dt = 100 A/μs		30	80	

Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)





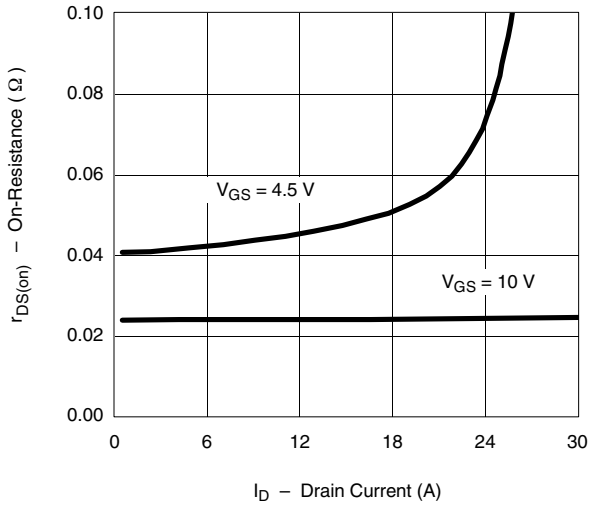
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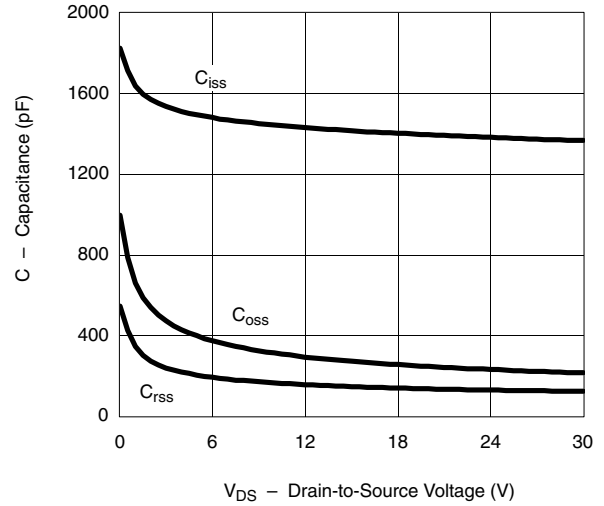
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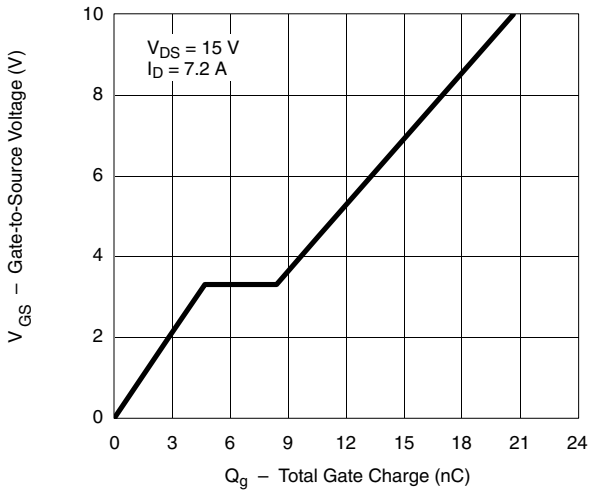
On-Resistance vs. Drain Current



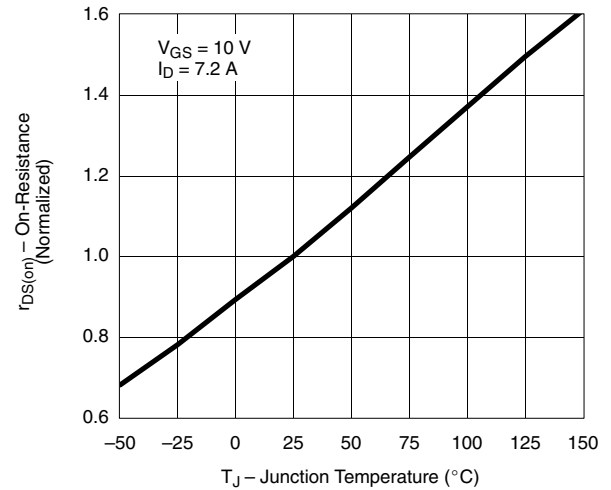
Capacitance



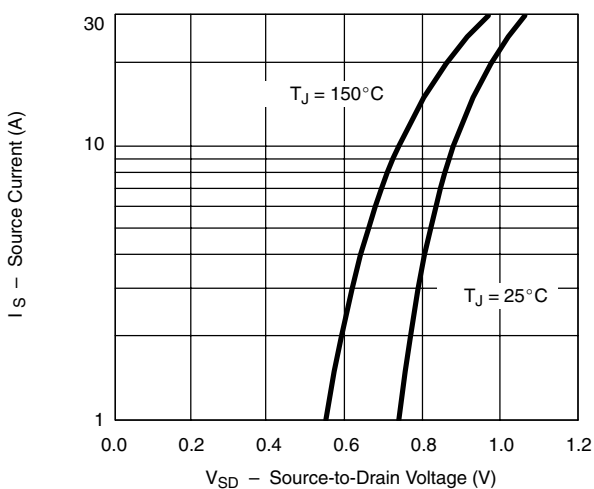
Gate Charge



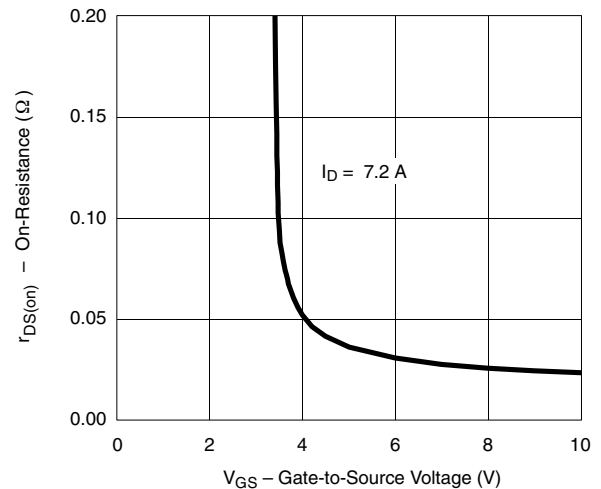
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage

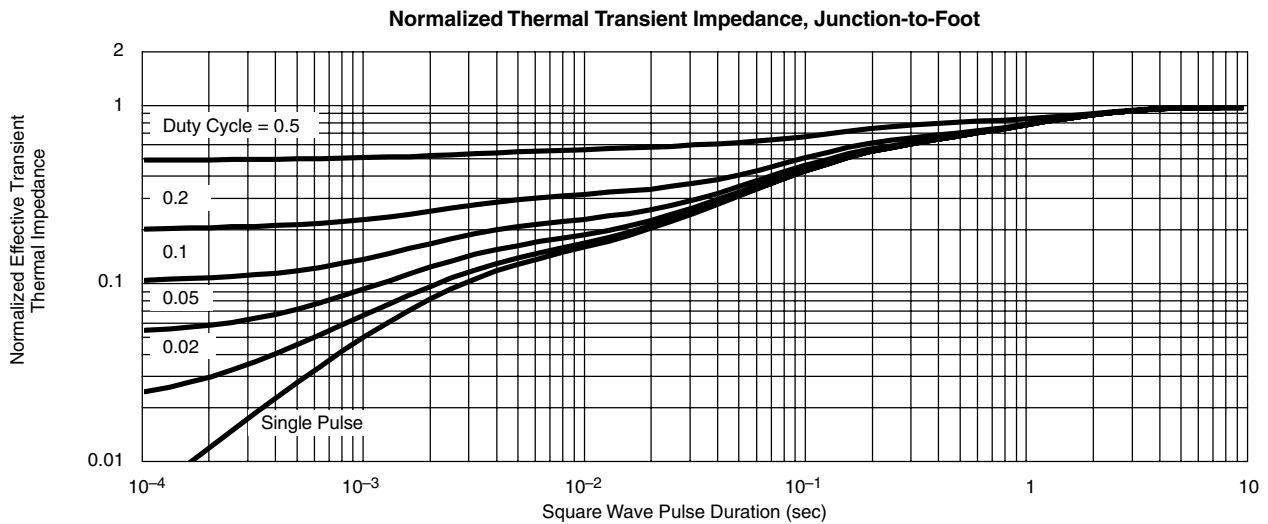
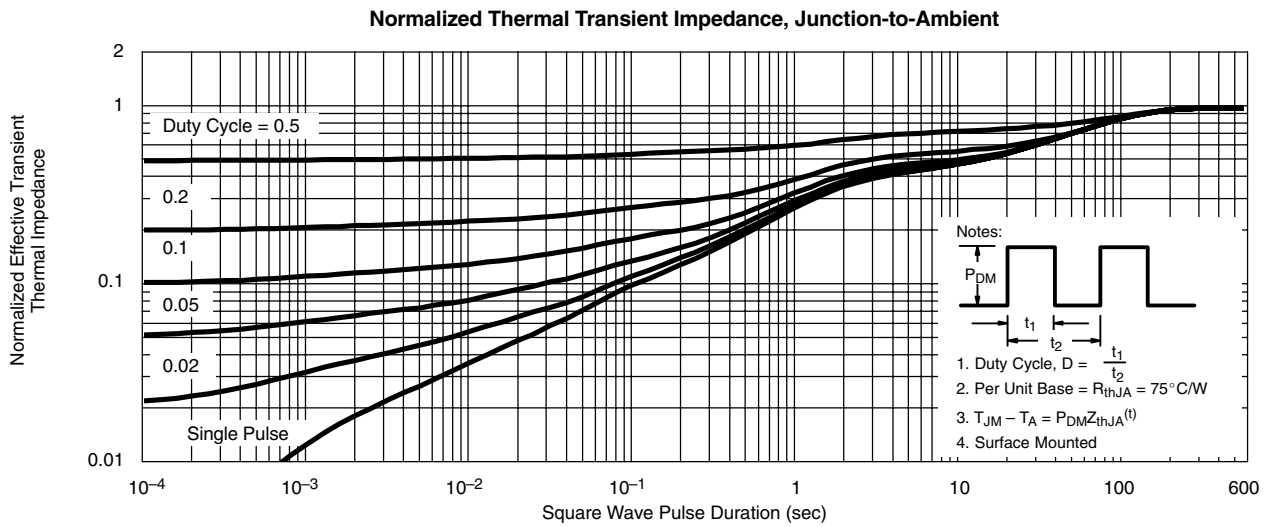
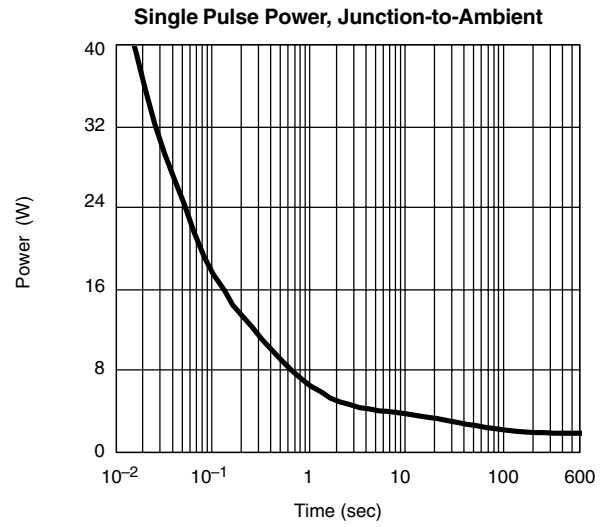
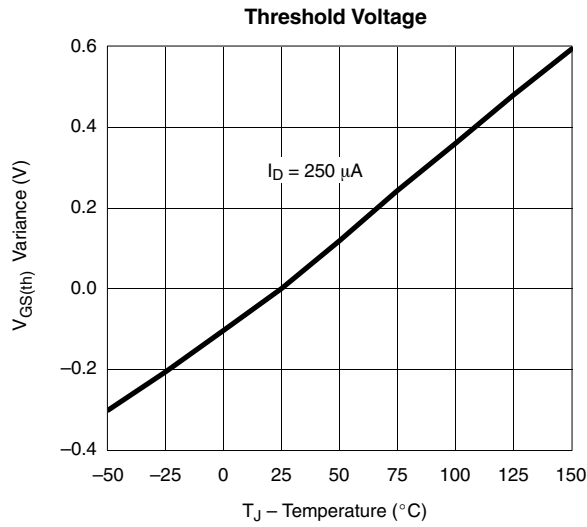


On-Resistance vs. Gate-to-Source Voltage





TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)





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